

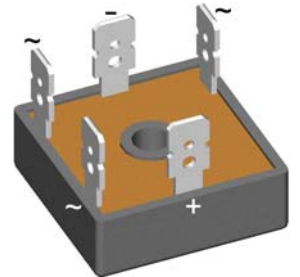
Standard Rectifier Module

3~ Rectifier	
V_{RRM}	= 1400 V
I_{DAV}	= 27 A
I_{FSM}	= 550 A

3~ Rectifier Bridge

Part number

VUO36-14N08



E72873



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour

Applications:

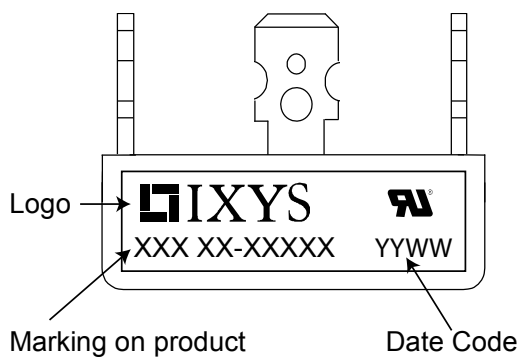
- Diode for main rectification
- For three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Package: FO-B

- Industry standard outline
- RoHS compliant
- ¼" fast-on terminals
- Easy to mount with one screw

Rectifier				Ratings				
Symbol	Definition	Conditions		min.	typ.	max.	Unit	
V_{RSM}	max. non-repetitive reverse blocking voltage					1500	V	
V_{RRM}	max. repetitive reverse blocking voltage					1400	V	
I_R	reverse current	$V_R = 1400$ V	$T_{VJ} = 25^\circ\text{C}$			40	μA	
		$V_R = 1400$ V	$T_{VJ} = 150^\circ\text{C}$			1.5	mA	
V_F	forward voltage drop	$I_F = 15$ A	$T_{VJ} = 25^\circ\text{C}$			1.04	V	
						1.23	V	
		$I_F = 45$ A	$T_{VJ} = 125^\circ\text{C}$			0.93	V	
						1.18	V	
I_{DAV}	bridge output current	$T_C = 85^\circ\text{C}$ rectangular $d = \frac{1}{3}$	$T_{VJ} = 150^\circ\text{C}$			27	A	
V_{FO}	threshold voltage	} for power loss calculation only				0.76	V	
r_F	slope resistance					9.1	m Ω	
R_{thJC}	thermal resistance junction to case					7	K/W	
R_{thCH}	thermal resistance case to heatsink				1		K/W	
P_{tot}	total power dissipation			$T_C = 25^\circ\text{C}$		17	W	
I_{FSM}	max. forward surge current	$t = 10$ ms; (50 Hz), sine	$T_{VJ} = 45^\circ\text{C}$			550	A	
						595	A	
		$t = 8,3$ ms; (60 Hz), sine	$V_R = 0$ V	$T_{VJ} = 150^\circ\text{C}$			470	A
							505	A
I^2t	value for fusing	$t = 10$ ms; (50 Hz), sine	$T_{VJ} = 45^\circ\text{C}$			1.52	kA ² s	
						1.48	kA ² s	
		$t = 8,3$ ms; (60 Hz), sine	$V_R = 0$ V	$T_{VJ} = 150^\circ\text{C}$			1.11	kA ² s
							1.06	kA ² s
C_J	junction capacitance	$V_R = 400$ V; $f = 1$ MHz		$T_{VJ} = 25^\circ\text{C}$		18	pF	

Package FO-B		Ratings				
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal			100	A
T_{stg}	storage temperature		-40		125	°C
T_{VJ}	virtual junction temperature		-40		150	°C
Weight				20		g
M_D	mounting torque		1.8		2.2	Nm
$d_{Spp/App}$	creepage distance on surface striking distance through air	terminal to terminal	9.0	7.0		mm
$d_{Spb/Apb}$		terminal to backside	10.0	10.0		mm
V_{ISOL}	isolation voltage	t = 1 second	3000			V
		t = 1 minute 50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA	2500			V



Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	VUO36-14NO8	VUO36-14NO8	Box	50	465151

Equivalent Circuits for Simulation

* on die level

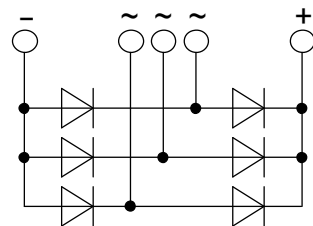
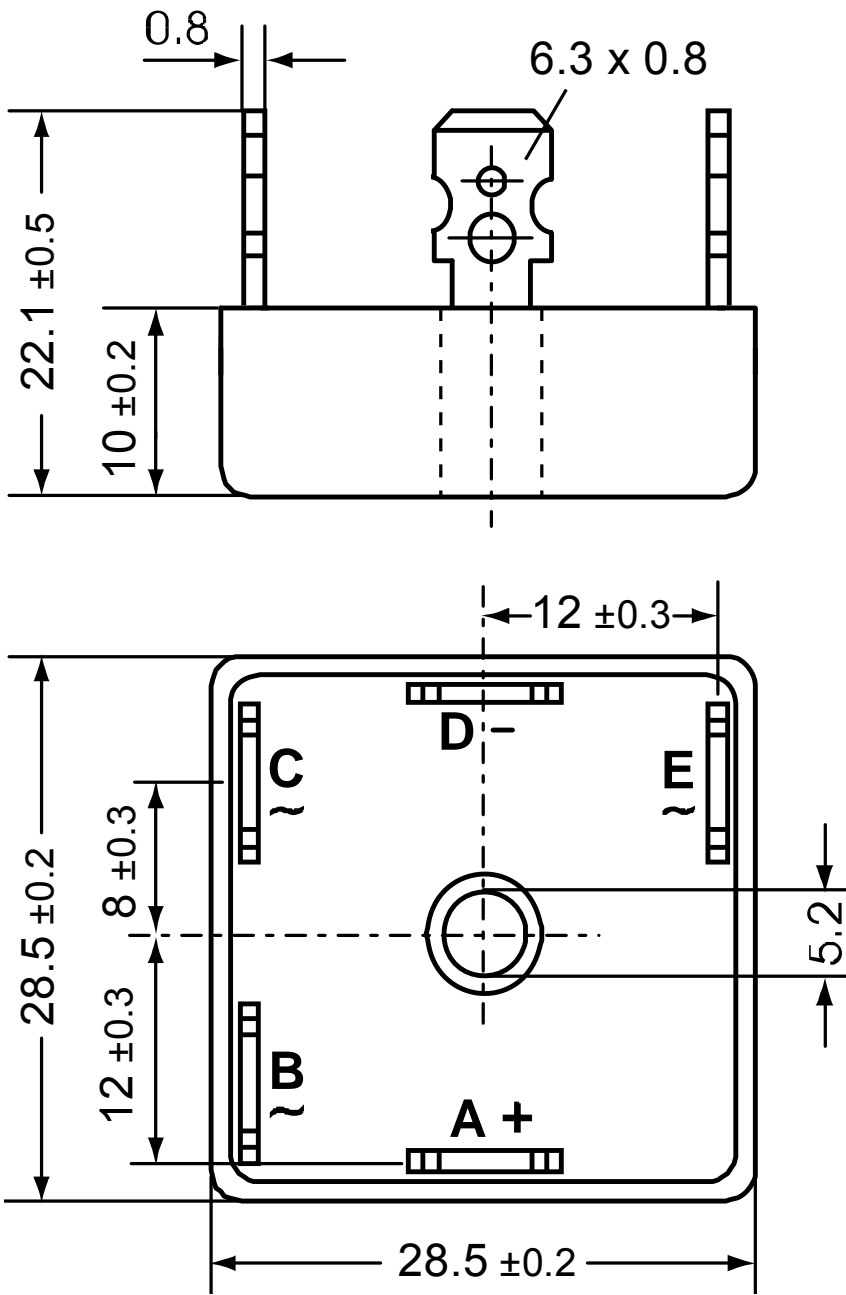
$T_{VJ} = 150^\circ\text{C}$



Rectifier

$V_{0\ max}$	threshold voltage	0.76	V
$R_{0\ max}$	slope resistance *	7.9	mΩ

Outlines FO-B



Rectifier

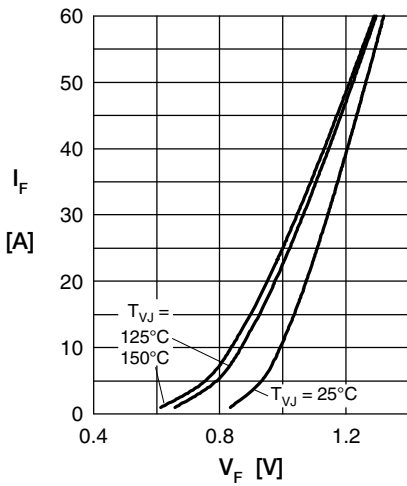


Fig. 1 Forward current vs. voltage drop per diode

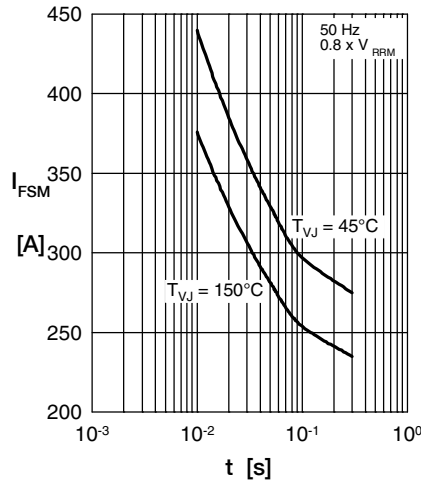


Fig. 2 Surge overload current vs. time per diode

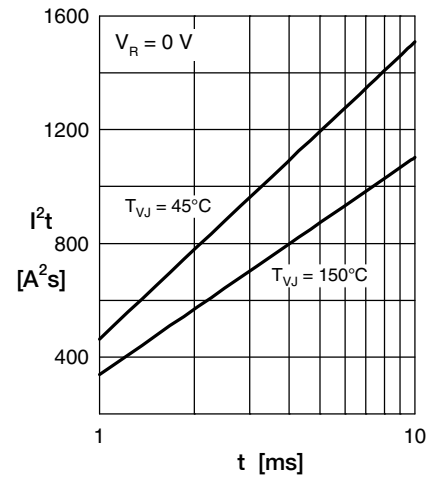


Fig. 3 I^2t vs. time per diode

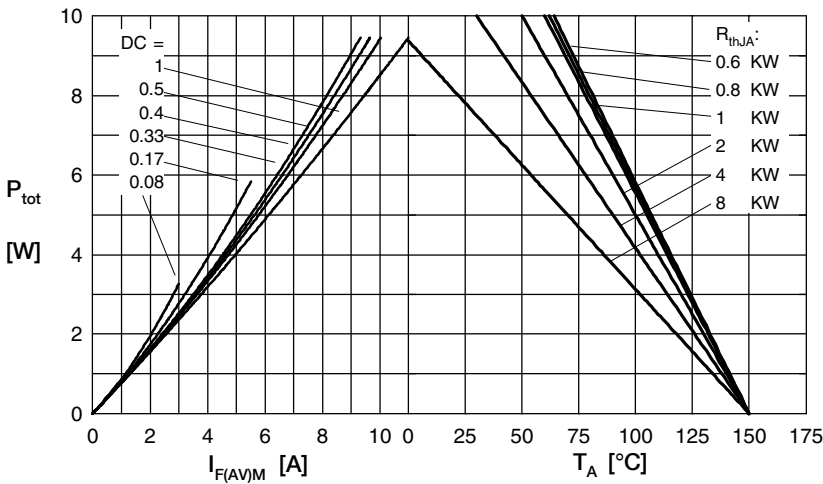


Fig. 4 Power dissipation vs. forward current and ambient temperature per diode

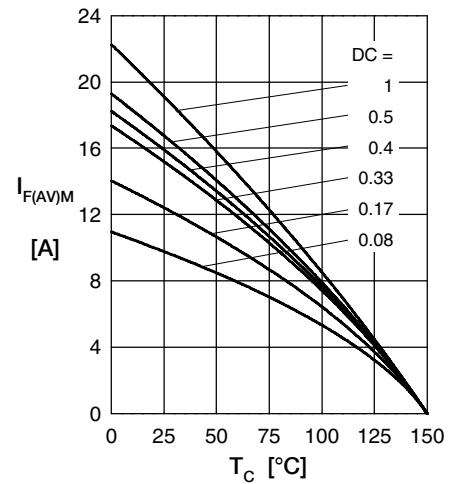


Fig. 5 Max. forward current vs. case temperature per diode

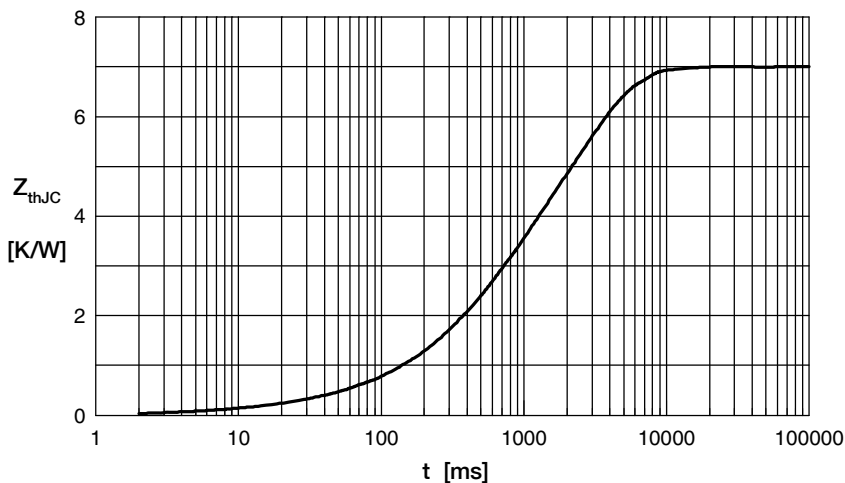


Fig. 6 Transient thermal impedance junction to case vs. time per diode

Constants for Z_{thJC} calculation:

i	R_{th} (K/W)	t_i (s)
1	0.040	0.005
2	0.150	0.030
3	1.710	0.400
4	5.100	2.300